

Radant MEMS Announces Exhibit at 2004 IEEE MTT-S

STOW, MA (May 10, 2004) - Radant MEMS, Inc. (RMI) today announced its plans to introduce its RF-MEMS switches at the 2004 IEEE MTT-S International Microwave Symposium/Exhibition.

“Radant MEMS Inc. is an industry leader in producing highly reliable RF-MEMS (DC to 40 GHz) switches with repeatable lifetimes greater than 10 billion and best case switch lifetimes of 100 billion cycles. These switches are hermetically sealed within a very small, low cost, wafer-capped package,” said Scott Rassouliau, RMI’s vice president of business development. “Our MEMS switches offer considerable reduction of insertion loss and excellent linearity when compared with the aforementioned alternate technologies and we look forward to the introduction of a variety of designs and configurations of our RF-MEMS at the 2004 MTT-S at our booth number 283.”

In addition, Dr. John Maciel, vice president and chief operating officer of Radant MEMS, Inc., will be presenting a paper on "Reliability Testing of Ohmic MEMS Switches" at the 2004 International Microwave Symposium in Fort Worth, TX. This presentation will be part of the Reliability in MEMS Switches Workshop to be held on June 11, 2004.

About Radant MEMS

Radant MEMS, Inc. is located in Stow, MA (www.radantmems.com). Radant MEMS is one of the industry leaders in producing highly reliable RF-MEMS “DC to 40 GHz” switches with repeatable lifetimes greater than 10 billion and best case switch lifetimes of 100 billion cycles. For additional information please contact Scott Rassouliau at Tel:978-562-3866 Ext-295